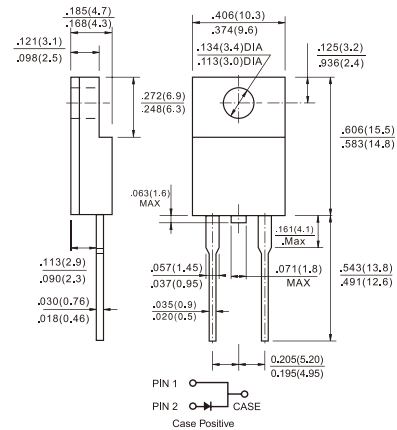




# MBRF735 - MBRF7150

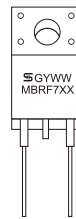
## Isolated 7.5 AMPS. Schottky Barrier Rectifiers

### ITO-220AC



Dimensions in inches and (millimeters)

Marking Diagram



MBRF7XX = Specific Device Code  
 G = Green Compound  
 Y = Year  
 WW = Work Week

### Features

- ✧ UL Recognized File # E-326243
- ✧ Plastic material used carries Underwriters Laboratory Classifications 94V-0
- ✧ Metal silicon rectifier, majority carrier conduction
- ✧ Low power loss, high efficiency
- ✧ High current capability, low forward voltage drop
- ✧ High surge capability
- ✧ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ✧ Guardring for overvoltage protection
- ✧ High temperature soldering guaranteed: 260°C/10 seconds, 0.25"(6.35mm) from case
- ✧ Green compound with suffix "G" on packing code & prefix "G" on datecode.

### Mechanical Data

- ✧ Cases: ITO-220AC molded plastic body
- ✧ Terminals: Pure tin plated, lead free. solderable per MIL-STD-750, Method 2026
- ✧ Polarity: As marked
- ✧ Mounting position: Any
- ✧ Mounting torque: 5 in. - lbs. max
- ✧ Weight: 1.69 grams

### Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.  
 Single phase, half wave, 60 Hz, resistive or inductive load.  
 For capacitive load, derate current by 20%

Type Number	Symbol	MBRF	MBRF	MBRF	MBRF	MBRF	MBRF	MBRF	Units	
		735	745	750	760	790	7100	7150		
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	35	45	50	60	90	100	150	V	
Maximum RMS Voltage	V <sub>RMS</sub>	24	31	35	42	63	70	105	V	
Maximum DC Blocking Voltage	V <sub>DC</sub>	35	45	50	60	90	100	150	V	
Maximum Average Forward Rectified Current See Fig. 1	I <sub>F(AV)</sub>	7.5							A	
Peak Repetitive Forward Current (Square Wave, 20KHz) at T <sub>c</sub> =105°C	I <sub>FRM</sub>	15							A	
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method )	I <sub>FSM</sub>	150							A	
Peak Repetitive Reverse Surge Current (Note 2)	I <sub>RRM</sub>	1.0			0.5				A	
Maximum Instantaneous Forward Voltage at I <sub>F</sub> =7.5A, T <sub>A</sub> =25 °C I <sub>F</sub> =7.5A, T <sub>A</sub> =125 °C I <sub>F</sub> =15A, T <sub>A</sub> =25 °C I <sub>F</sub> =15A, T <sub>A</sub> =125 °C	V <sub>F</sub>	-	0.57	0.84	0.72	0.75	0.65	0.92	1.02	V
Maximum Instantaneous Reverse Current @ T <sub>A</sub> =25 °C at Rated DC Blocking Voltage (Note 1) @ T <sub>A</sub> =125 °C	I <sub>R</sub>	0.1	15	0.1	10	0.1	5.0	0.1	5.0	mA mA
Voltage Rate of Change (Rated V <sub>R</sub> )	dV/dt	10,000							V/uS	
Typical Junction Capacitance	C <sub>j</sub>	350		280		200			pF	
Maximum Thermal Resistance, (Note 3)	R <sub>θJC</sub>	7.0							°C/W	
Operating Junction Temperature Range	T <sub>J</sub>	-65 to +150							°C	
Storage Temperature Range	T <sub>STG</sub>	-65 to +175							°C	

Notes: 1. Pulse Test: 300us Pulse Width, 1% Duty Cycle  
 2. 2.0us Pulse Width, f=1.0 KHz  
 3. Mounted on Heatsink Size of 2 in x 3 in x 0.25in Al-plate.

## RATINGS AND CHARACTERISTIC CURVES (MBRF735 THRU MBRF7150)

FIG.1- FORWARD CURRENT DERATING CURVE

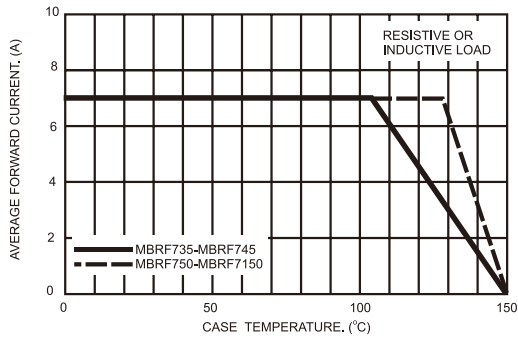


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

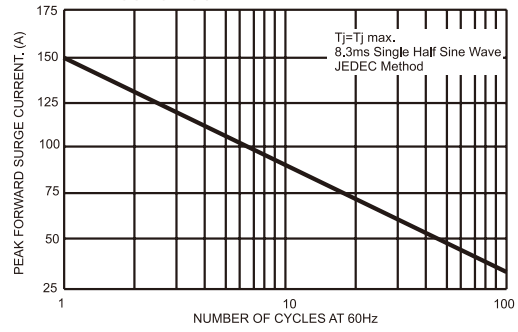


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

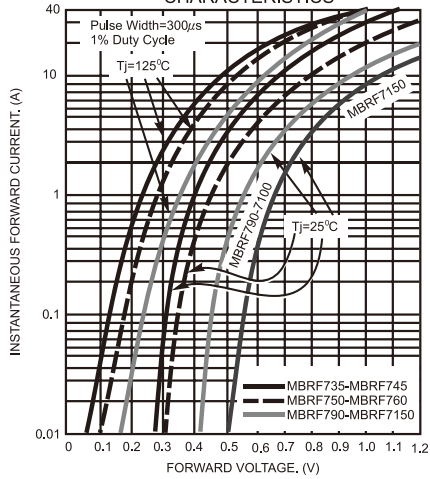


FIG.4- TYPICAL REVERSE CHARACTERISTICS

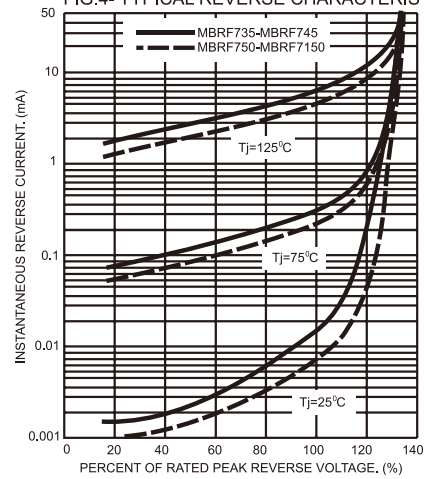


FIG.5- TYPICAL JUNCTION CAPACITANCE

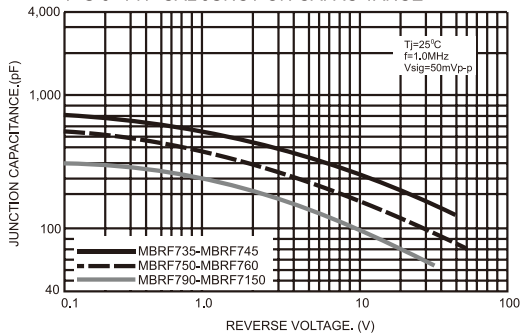


FIG.6- TYPICAL TRANSIENT THERMAL CHARACTERISTICS

